## NSN 5961-00-229-7778

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.104 inches
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1.5 forward voltage, average
Current Rating Per Characteristic:
200.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
No
Fiig:
A110a0